PATENTS

## Attorney Docket No.: ELM-2 Cont. 4

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

: Glenn J. Leedy

Application No.

: 10/672,961 Confirmation No.: 9439

Filed

APR 2 7 2007

Applicant

: September 26, 2003

For

: THREE DIMENSIONAL MULTI LAYER MEMORY AND

CONTROL LOGIC INTEGRATED CIRCUIT

STRUCTURE

Group Art Unit : 2822

Examiner

: Monica Lewis

Mail Stop AMENDMENT Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450

#### SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with 37 C.F.R. §§ 1.56 and 1.97, applicant wishes to call the attention of the Examiner to the following documents:

#### Foreign Patent Documents

DE	3233195	03/17/1983	Mitsubishi Electric
ביע	3233133	03/11/1303	Corporation
JP	2037655	02/07/1990	Siemens AG
JP	3127816	05/30/1991	Canon KK
JP	3174715	07/29/1991	Fujitsu Limited
WO	98/19337	05/07/1998	Trusi Technologies,

#### Nonpatent Literature Documents

Wolf, Stanley and Richard N. Tauber; Silicon Processing For the VLSI Era, Volume 1: Process Technology; Sunset Beach, CA: Lattice Press,

1986, pages 191-194

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Allen, Mark G.,: Senturia, Stephen D.; "Measurement of polymide interlayer adhesion using microfabricated structures"; 1988; pp. 352-356.

Kochugova, I.V.; Nikolaeva, L.V.; Vakser, N.M., (M.I. Kalinin Leningrad Polytechnic Institute (USSR); "Electrophysical investigation of thin-layered inorganic coatings"; 1989; pp. 826-828.

The aforementioned references are listed on the accompanying Form PTO/SB/08 (submitted in duplicate). Pursuant to 37 C.F.R. 1.98 (a)(2), copies of the aforementioned Foreign Patent Documents and Non-Patent Literature Documents are enclosed herewith.

Applicant reserves the right to establish the patentability of the claimed invention over any of the information provided herewith, and/or to prove that this information may not be prior art, and/or to prove that this information may not be enabling for the teachings purportedly offered.

The above-identified documents were previously cited in an Information Disclosure Statement filed on September 26, 2006, and were not considered by the Examiner. These references are being re-submitted herewith for the Examiner's consideration.

It is respectfully requested that these references be:

(1) fully considered by the Patent and Trademark Office during the examination of this application; and (2) printed on any patent which may issue on this application. Applicant requests that a copy of Form PTO-SB/08, as considered and initialed by the Examiner, be returned with the next communication.

This Statement is submitted with a Request for Continued Examination under 37 C.F.R. § 1.114. The Director is hereby authorized to charge \$180.00 in payment of the fee for submission of this Information Disclosure Statement pursuant to 37 C.F.R. §1.97(c)(2), payment of any additional fees required in connection with this Statement, or to credit any overpayment of the same, to Deposit Account No. 06-1075 (Order No.: 001202-0127). A duplicate copy of this Information Disclosure Statement is enclosed herewith.

An early and favorable action is respectfully requested.

Respectfully submitted,

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PTO/SB/08a/b (08-03)

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Complete if Known Substitute for form 1449A/B/PTO 10/672,961 (Conf. No. 9439) Application Number INFORMATION DISCLOSURE September 26, 2003 Filing Date STATEMENT BY APPLICANT First Named Inventor Glenn J. Leedy Art Unit 2822 (Use as many sheets as necessary) Examiner Name Monica Lewis

ELM-2 CONT. 4 Sheet 1 of Attorney Docket Number **U.S. PATENT DOCUMENTS** Pages, Columns, Lines, Where **Document Number Publication Date** Examiner Name of Patentee or Cite Relevant Passages or Relevant MM-DD-YYYY Number-Kind Code<sup>2</sup> ( if known) Applicant of Cited Document Initials\* Figures Appear

FOREIGN PATENT DOCUMENTS							
Examiner	Cite	Foreign Patent Document	Publication	Name of Patentee or	Pages, Columns, Lines,		
Initials*	No.1		Date MM-DD-YYYY	1 VV	Where Relevant Passages or Relevant Figures Appear	T⁵	
		DE3233195	03-17-1983	Mitsubishi Electric Corp.			
		JP2037655	02-07-1990	Siemens AG		Г	
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		JP3174715	07-29-1991	Fujitsu Limited			
		WO 98/19337	05-07-1998	Trusi Technologies, LLC			

	NON PATENT LITERATURE DOCUMENTS						
Examiner Initials Cite No.1 Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (I magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, or and/or country where published.							
		Wolf, Stanley and Richard N. Tauber; Silicon Processing For the VLSI Era, Volume 1: Process Technology; Sunset Beach, CA: Lattice Press, 1986, pages 191-194					
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Examiner	Date	
Signature	Considered	



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Sub	ostitute for form 1449A/B/PT	0		Complete if Known		
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11	NFORMATION	I DI	SCLOSURE	Filing Date	September 26, 2003	
STATEMENT BY APPLICANT				First Named Inventor	Glenn J. Leedy	
				Art Unit	2822	
(Use as many sheets as necessary)				Examiner Name	Monica Lewis	
Sheet	1	of	1	Attorney Docket Number	ELM-2 CONT. 4	

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